

Supporting Information

Study on Importance of Uniformity and Nanoparticle Size of ZIF-8 Carbon Nanoarchitecture for Enhancing Electrochemical Property

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Table S1. Summary of the synthesis conditions for all samples.

Samples	Zn(OAc) ₂ (g)	2-mIm (g)	Water content (mL)	Pouring time (s)	Pour order	Stirring
ZIF-8-m1	1.5	6.73	25	30	Zn to 2-mIm	750 rpm
ZIF-8-m2		6.73	25	3	Zn to 2-mIm	750 rpm
ZIF-8-m3		6.73	25	1	Zn to 2-mIm	750 rpm
ZIF-8-m4		6.73	35	1	Zn to 2-mIm	750 rpm
ZIF-8-m5		5.21	25	1	Zn to 2-mIm	750 rpm
ZIF-8-n		6.73	25	1	2-mIm to Zn	200 rpm

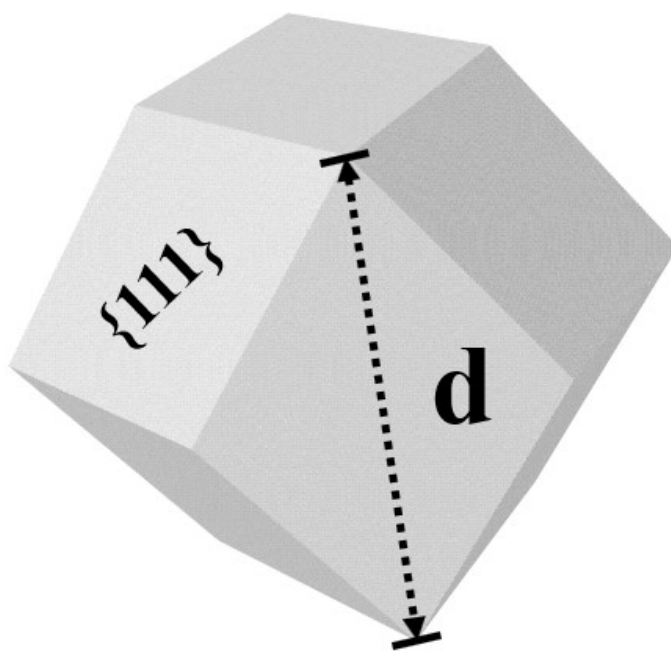


Figure S1. Schematic illustration of the measurement of the size (d) of the ZIF-8 particle with a rhombic dodecahedron shape.

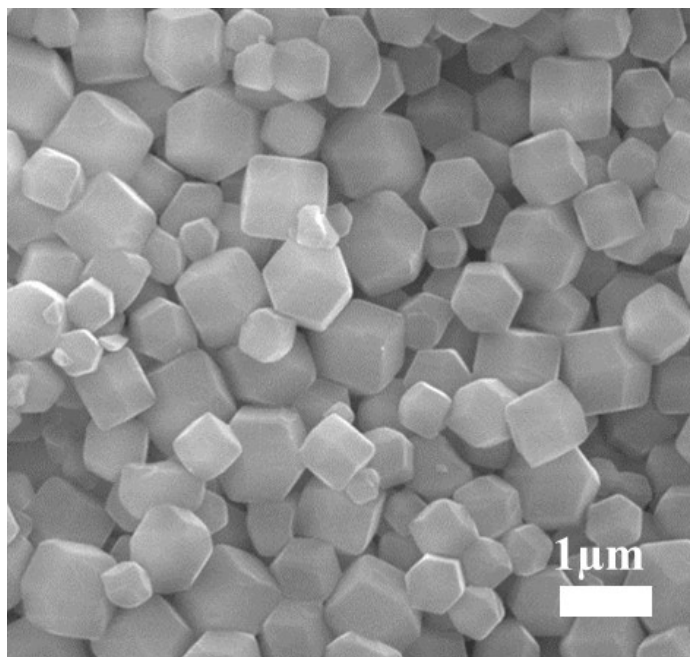


Figure S2. Scanning electron microscopy (SEM) images of ZIF-8-n.

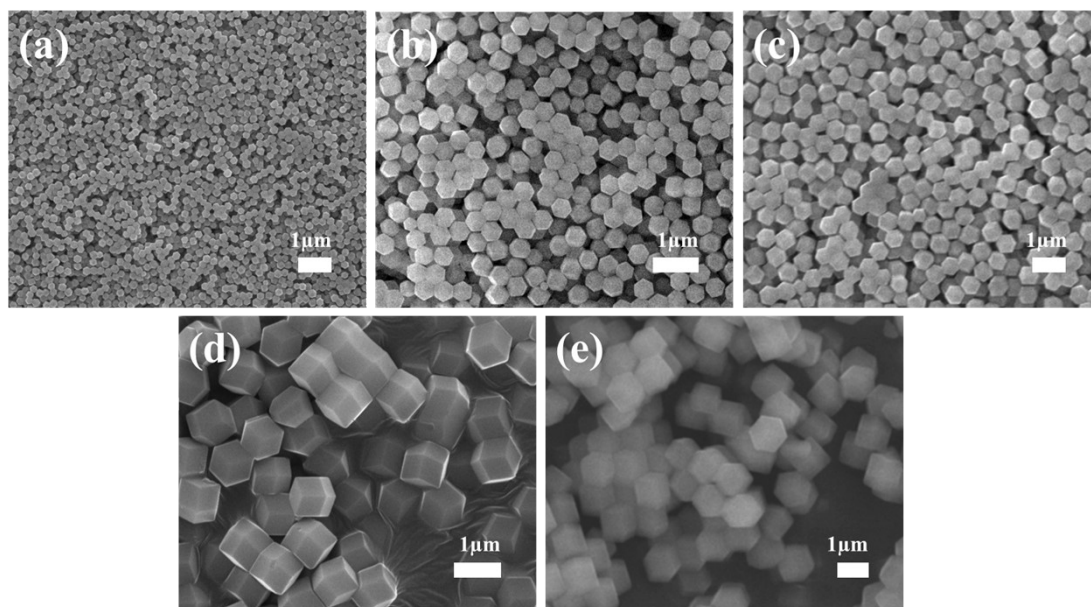


Figure S3. SEM images of (a) ZIF-8-m1, (b) ZIF-8-m2, (c) ZIF-8-m3, (d) ZIF-8-m4, and (e) ZIF-8-m5.

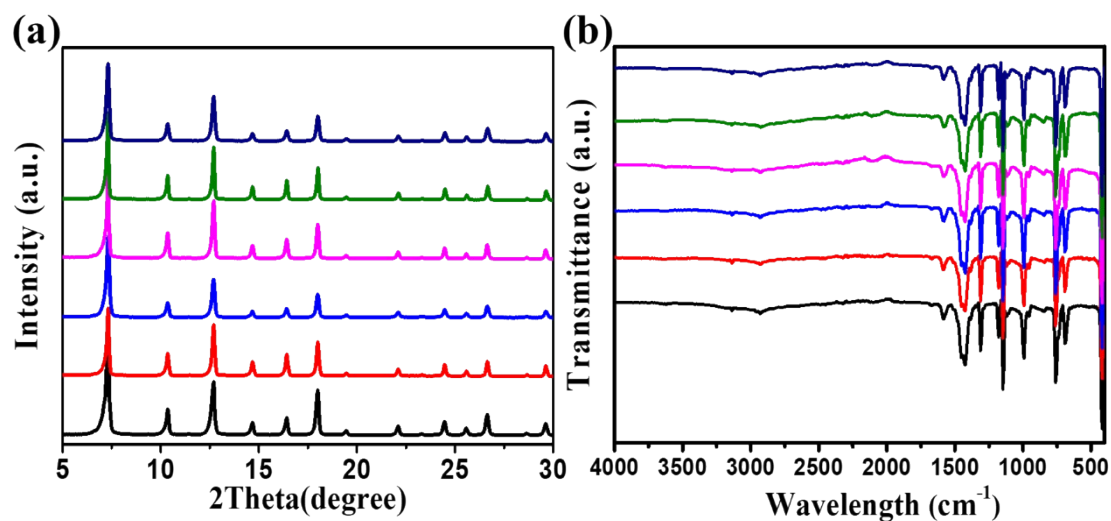


Figure S4. (a) X-ray diffraction (XRD) patterns and (b) Fourier transform infrared (FT-IR) spectra (Black: ZIF-8-m1, Red: ZIF-8-m2, Blue: ZIF-8-m3, Pink: ZIF-8-m4, Green: ZIF-8-m5, Navy: ZIF-8-n).

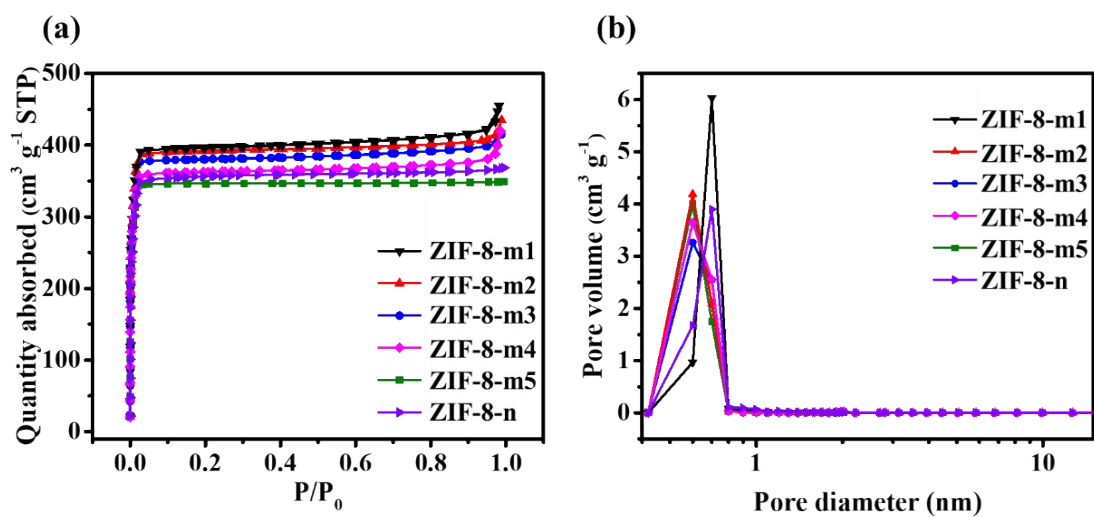


Figure S5. (a) N₂ adsorption-desorption isotherms, and (b) pore size distribution of the ZIF-8 samples.

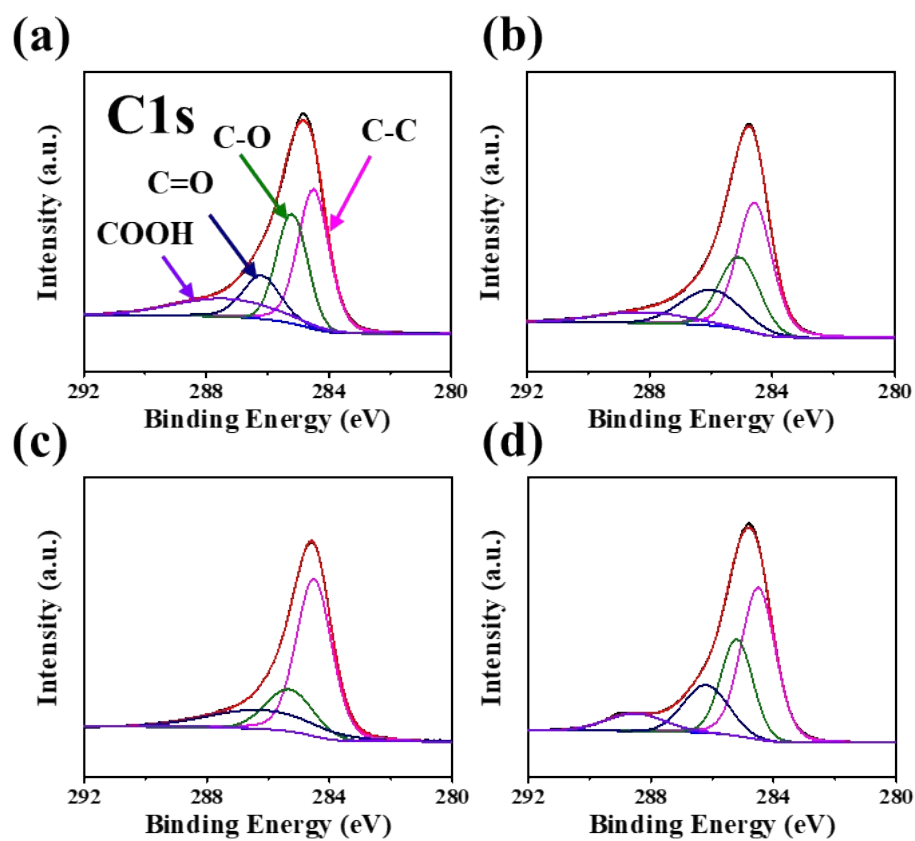


Figure S6. X-ray photoelectron spectroscopy (XPS) profiles of the C1s of (a) ZIF-8-C-m2, (b) ZIF-8-C-m3, (c) ZIF-8-C-m4, and (d) ZIF-8-C-m5.

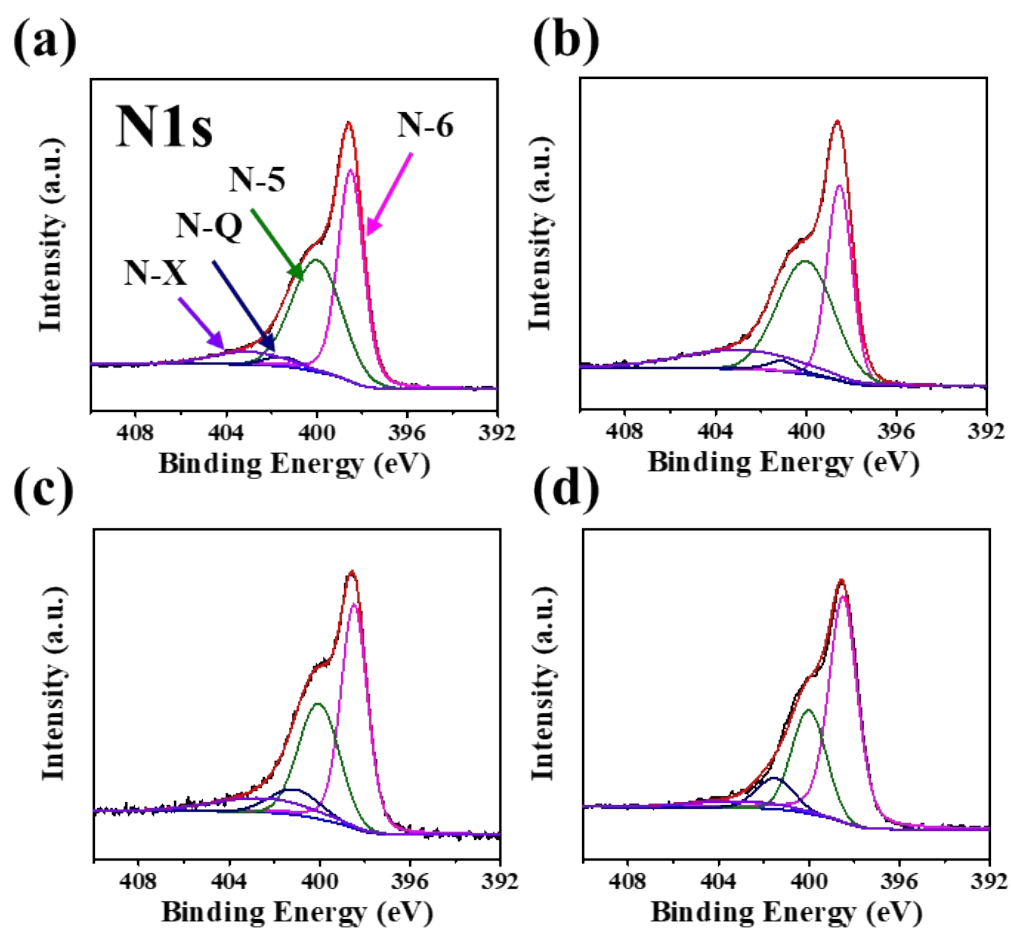


Figure S7. N1s XPS profiles of: (a) ZIF-8-C-m2, (b) ZIF-8-C-m3, (c) ZIF-8-C-m4, and (d) ZIF-8-C-m5.

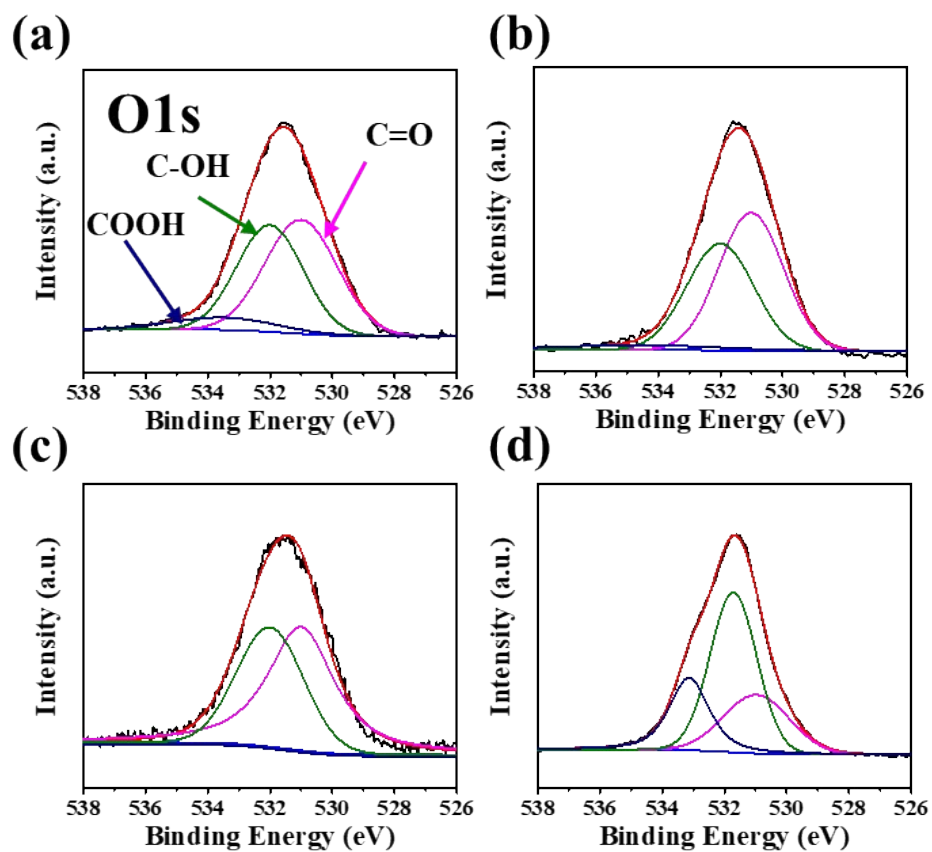


Figure S8. O1s XPS profiles of: (a) ZIF-8-C-m2, (b) ZIF-8-C-m3, (c) ZIF-8-C-m4, and (d) ZIF-8-C-m5.

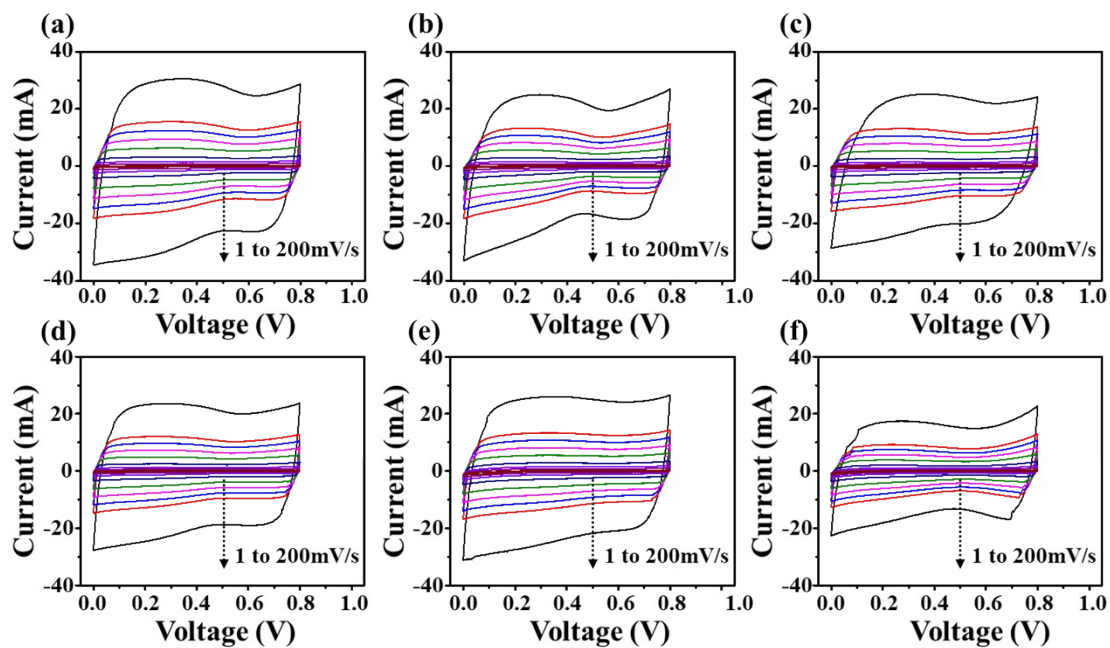


Figure S9. Cyclic voltammetry (CV) curves of (a): ZIF-8-C-m1 (b): ZIF-8-C-m2, (c): ZIF-8-C-m3, (d): ZIF-8-C-m4, (e): ZIF-8-C-m5, (f): ZIF-8-C-n at 1, 2, 5, 10, 20, 40, 60, 80, 100, and 200 mV s^{-1} .

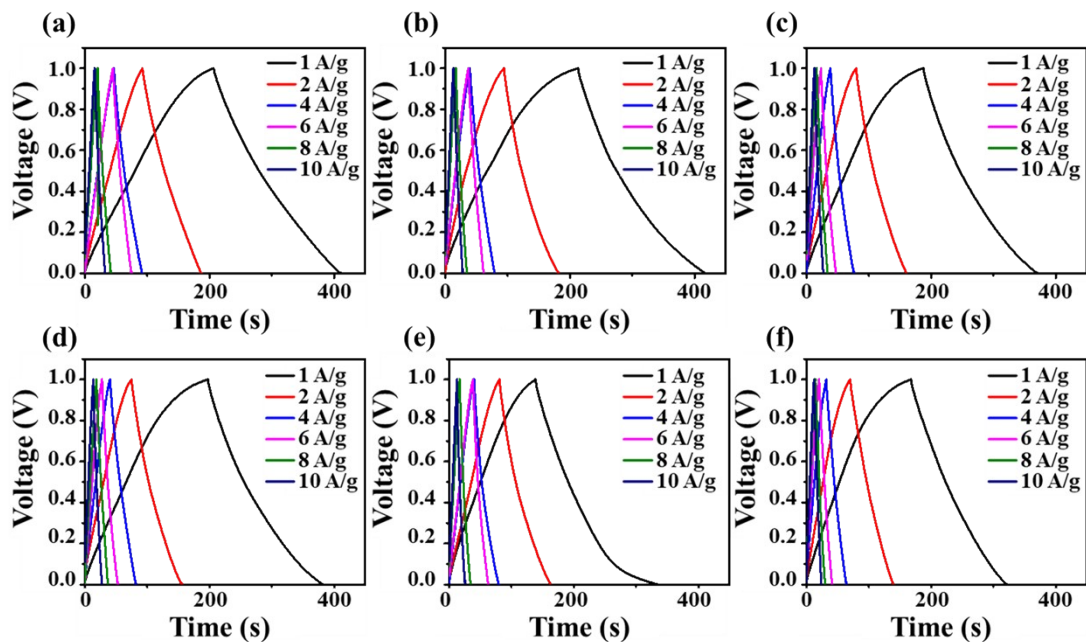


Figure S10. CV and galvanostatic charge-discharge (GCD) curves of: (a) ZIF-8-C-m1, (b) ZIF-8-C-m2, (c) ZIF-8-C-m3, (d) ZIF-8-C-m4, (e) ZIF-8-C-m5, and (f) ZIF-8-C-n at 1, 2, 4, 6, 8, 10 A g^{-1} .

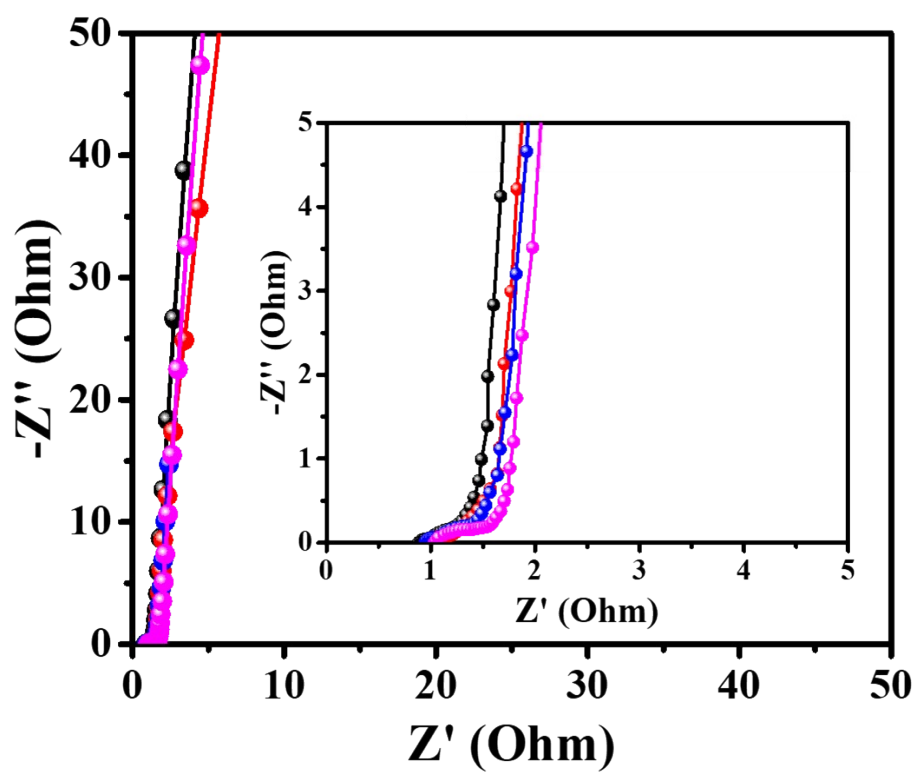


Figure S11. Nyquist plots of ZIF-8-C-m2 (black), ZIF-8-C-m3 (red), ZIF-8-C-m4 (blue), and ZIF-8-C-m5 (pink).

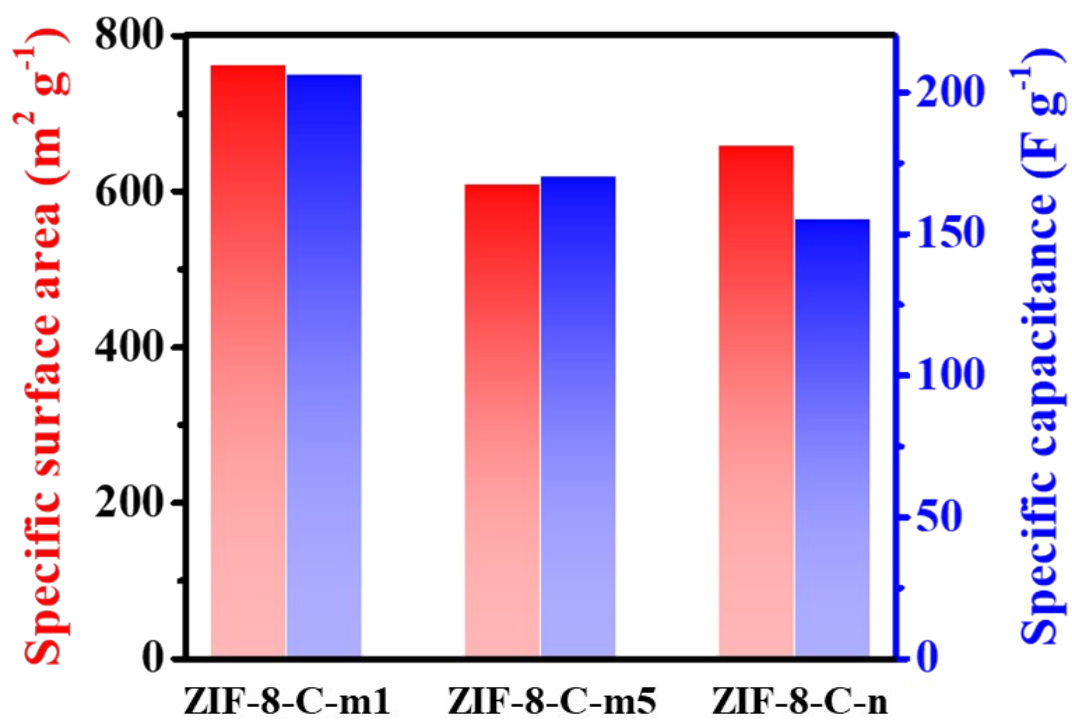


Figure S12. Comparison of the relative specific surface area and specific capacitance of ZIF-8-C-m1, ZIF-8-C-m5, and other ZIF-8-C-n samples.

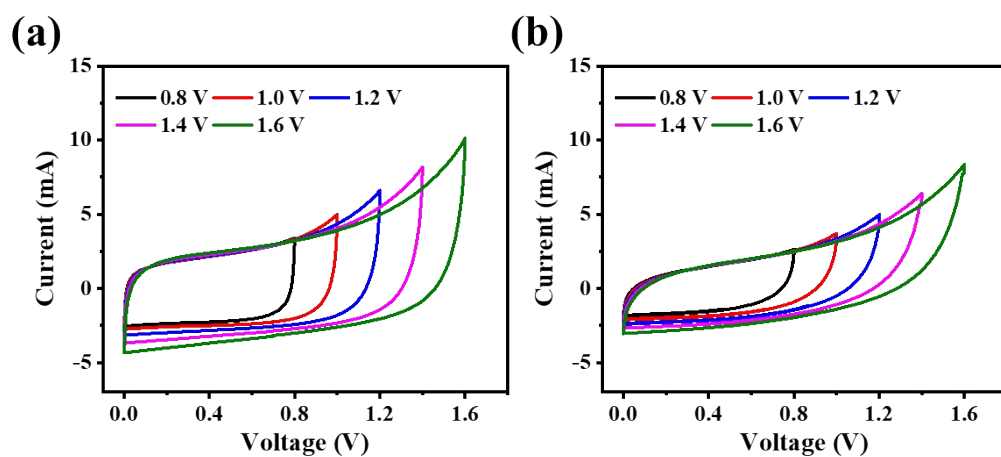


Figure S13. CV curves at $50 \text{ mV} \cdot \text{s}^{-1}$ under different voltage windows of ZIF-8-C-m5, and ZIF-8-C-n in the two-electrode system.

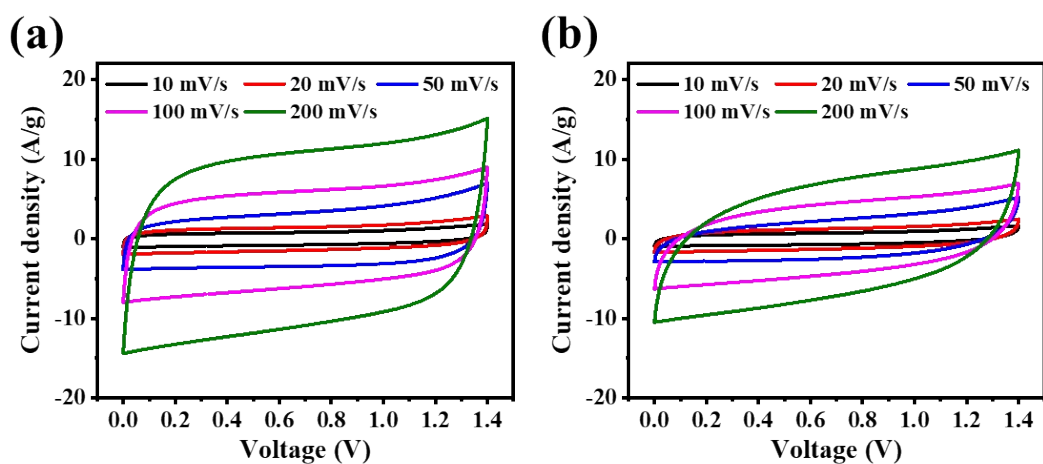


Figure S14. CV curves at different scan rates from 10 to $200 \text{ mV} \cdot \text{s}^{-1}$ of ZIF-8-C-m5, and ZIF-8-C-n in the two-electrode system.

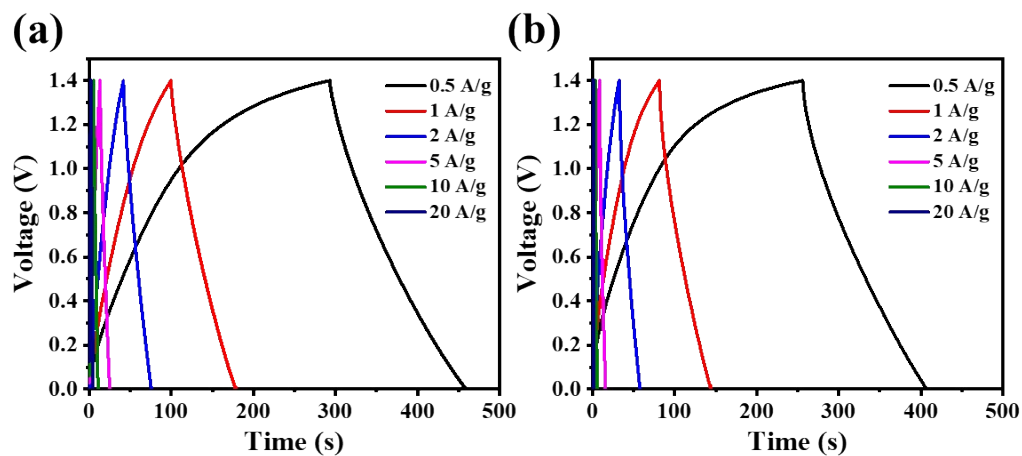


Figure S15. GCD curves at various current densities ($0.5\text{--}20\text{ A}\cdot\text{g}^{-1}$) of ZIF-8-C-m5, and ZIF-8-C-n in the two-electrode system.

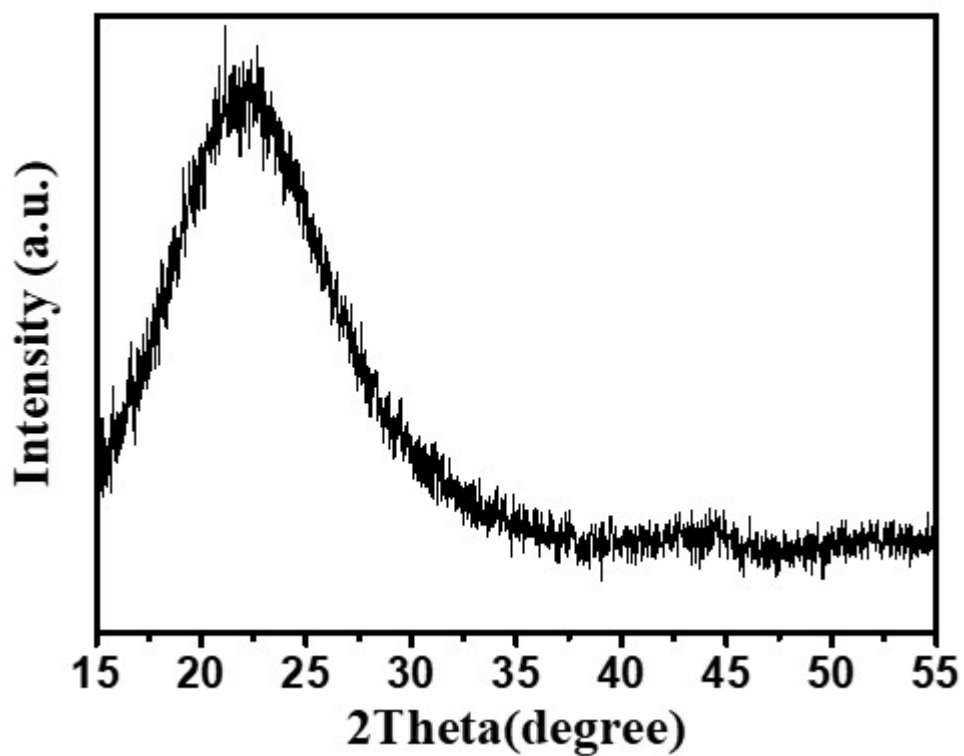


Figure S16. Ex-situ XRD patterns of ZIF-8-C-m1 after 10,000 cycle stability test in the flexible symmetric device system.

Table S2. Results of the BET analysis of the ZIF-8-derived carbon with different particle sizes.

Sample	S_{bet} (m ² /g)	V_{total} (cm ³ /g)	V_{micro} (cm ³ /g)	D_{avg} (nm)
ZIF-8-m1	1206.5	0.7039	0.5998	1.27
ZIF-8-m2	1119.2	0.6325	0.5627	1.14
ZIF-8-m3	1110.1	0.6249	0.5729	1.10
ZIF-8-m4	1092	0.6021	0.5539	1.24
ZIF-8-m5	1040.2	0.5926	0.5793	1.11
ZIF-8-n	1073.2	0.5821	0.5402	1.14

Table S3. XPS data of the ZIF-8 and ZIF-8-C samples.

Sample	C (at%)	N (at%)	O (at%)	Zn (at%)
ZIF-8-m1	62.11	27.89	1.29	8.71
ZIF-8-C-m1	76.93	16.11	6.96	-
ZIF-8-C-m2	78.6	15.77	5.63	-
ZIF-8-C-m3	81.15	12.77	6.08	-
ZIF-8-C-m4	81.13	12.91	5.96	-
ZIF-8-C-m5	81.5	11.31	7.19	-
ZIF-8-C-n	79.22	11.31	9.47	-

Table S4. Specific capacitance (F g^{-1}) of the ZIF-8-C samples calculated from the CV curves obtained at different scan rates.

Scan rate (mV s^{-1})	ZIF-8-C-m1	ZIF-8-C-m2	ZIF-8-C-m3	ZIF-8-C-m4	ZIF-8-C-m5	ZIF-8-C-n
1	178.47	156.56	164.14	150.48	140.53	112.02
5	165.28	143.39	142.47	138.31	130.21	109.12
10	162.36	140.43	137.57	136.68	129.60	107.43
20	158.21	134.47	133.25	132.72	126.12	103.33
40	153.13	127.68	128.47	127.72	122.07	98.14
60	149.43	122.94	125.31	124.13	119.26	94.73
80	146.31	119.24	122.77	121.37	116.96	91.96
100	143.64	116.15	120.52	118.79	114.99	89.65
200	132.54	103.97	111.12	100.91	107.19	80.37

Table S5. Specific capacitance (F g^{-1}) of the ZIF-8-C samples calculated from the GCD curves at different current densities.

Current densities (A g^{-1})	ZIF-8-C-m1	ZIF-8-C-m2	ZIF-8-C-m3	ZIF-8-C-m4	ZIF-8-C-m5	ZIF-8-C-n
1	206.4	201.54	196.54	193	183.27	155.34
2	188.02	189.01	172.73	173.36	150.52	142.2
4	180.18	170.89	163.64	166.72	139.71	131.32
6	175.38	158.91	160.53	151.1	132.54	124.26
8	168.8	152.19	146.49	146.2	130.87	120
10	165.6	149	142.3	138.8	125.42	117.8

Table S6. Series resistance (R_s) and charge transfer resistance (R_{ct}) of ZIF-8-C samples estimated from the Nyquist plot.

	ZIF-8-C-m1	ZIF-8-C-m2	ZIF-8-C-m3	ZIF-8-C-m4	ZIF-8-C-m5	ZIF-8-C-n
R_s (Ω)	0.9145	0.93405	0.97758	0.95804	1.0376	1.0253
R_{ct} (Ω)	0.2124	0.2323	0.2334	0.4187	0.493	0.5718

Table S7. Comparison of the specific capacitance of various previously reported ZIF-8-derived carbon materials for supercapacitors.

Samples	Specific capacitance (F·g ⁻¹)	Current density (A·g ⁻¹)	Cycle number	Capacitance retention (%)	Particle size (nm)	Power density (W·kg ⁻¹)	Energy density (Wh·kg ⁻¹)	Ref
MPC	148.4	2	-	-	85	-	-	1
CNT@CZIF-1	168	0.5	1,000	86.40	20	-	-	2
C-ZIF-8	155.9	1	10,000	95.5	50	-	-	3
NCGs	225	0.5	10,000	96.60	50	447	12.7	4
C(ZIF-8)	130	1	-	-	100	-	-	5
PC-900	173	1	-	-	150	650	7.5	6
NPC	184.4	1	-	-	200	-	-	7
N-HPC-900	182.5	0.2	5,000	94.79	200	50	4.46	8
ZPC-900	185.9	1	-	-	800	-	-	9
HPC NPs	134.5	1	10,000	90.70	480	-	-	10
Assy-ZIF-8-DC	170	1	60,000	96.00	110	105	5.9	11
ZIF-8/GO	95	1	-	-	500	-	-	12
This work	206.4	1	10,000	99.65	147	350	19.4	-

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